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				First Named Inventor	Kenneth R. Burch	70
				Group Art Unit		7.1
				Examiner Name		
Sheet	1	of	2	Attorney Docket Number	SC11767TC	-

			U. S	S. PATENT DOCUMENTS		
Examiner Initials*	Cite No. 1	U.S. Patent Number Code ²	Document Kind (if known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
Mu).		5,654,588		Dasse et al.	Aug.5,1997	
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		OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No. 1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
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Examiner Signature	MUIRZEWSKI	Date Considered	9/03	

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